

**Features**

- Solid-state Silicon technology
- Ultra Low Capacitance
- Low Clamping Voltage
- Halogen Free. "Green" Device (Note 1)
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

**Maximum Ratings**

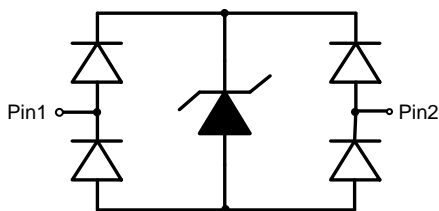
- Operating Junction Temperature Range: -55°C to +125°C
- Storage Temperature Range: -55°C to +150°C

| MCC Part Number | Device Marking |
|-----------------|----------------|
| ESDSBSLC5V0AE2  | U5             |

|                            |                 |                |
|----------------------------|-----------------|----------------|
| IEC61000-4-2(ESD)          | Air Contact     | ±15KV<br>±15KV |
| Peak Pulse Current(8/20µs) | I <sub>PP</sub> | 4A             |
| Peak Pulse Power (8/20µs)  | P <sub>PK</sub> | 44W            |

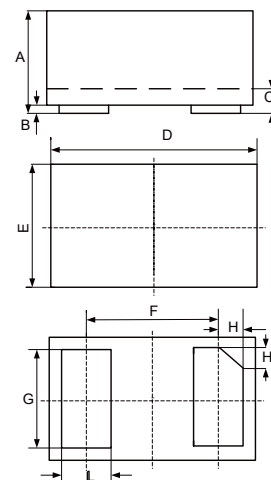
Note: 1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

**Internal Structure**



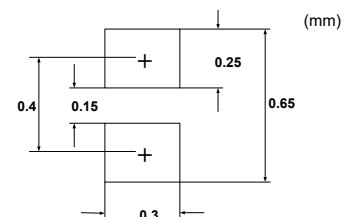
**Snap Back  
ESD Protection  
Device**

**0201-A**



| DIM | INCHES |       | MM    |      | NOTE |
|-----|--------|-------|-------|------|------|
|     | MIN    | MAX   | MIN   | MAX  |      |
| A   | 0.009  | 0.013 | 0.23  | 0.33 |      |
| B   | 0.000  | 0.002 | 0.00  | 0.05 |      |
| C   | 0.005  | 0.007 | 0.12  | 0.18 |      |
| D   | 0.022  | 0.026 | 0.55  | 0.65 |      |
| E   | 0.010  | 0.014 | 0.25  | 0.35 |      |
| F   | 0.014  |       | 0.355 |      | TYP. |
| G   | 0.008  | 0.011 | 0.22  | 0.28 |      |
| H   | 0.003  |       | 0.079 |      | TYP. |
| L   | 0.006  | 0.009 | 0.16  | 0.22 |      |

**SUGGESTED SOLDER PAD LAYOUT**



**Electrical Characteristics @ 25°C (Unless Otherwise Specified)**

| Parameter                              | Symbol    | Conditions                 | Min. | Typ. | Max. | Units    |
|--|-----------|----------------------------|------|------|------|----------|
| Reverse Working Voltage                | $V_{RWM}$ |                            |      |      | 5    | V        |
| Reverse Breakdown Voltage              | $V_{BR}$  | $I_T = 1mA$                | 6    | 8    |      | V        |
| Reverse Leakage Current                | $I_R$     | $V_{RWM}=3.3V$             |      | <1   | 50   | nA       |
| Clamping Voltage <sup>(Note 1)</sup>   | $V_C$     | $I_{PP}=16A, t_p=100ns$    |      | 14   |      | V        |
| Dynamic Resistance <sup>(Note 1)</sup> | $R_{DYN}$ |                            |      | 0.55 |      | $\Omega$ |
| Clamping Voltage <sup>(Note 2)</sup>   | $V_C$     | $V_{ESD}=8KV$              |      | 14   |      | V        |
| Clamping Voltage <sup>(Note 3)</sup>   | $V_C$     | $I_{PP}=1A, t_p=8/20\mu s$ |      | 8.3  |      | V        |
| Clamping Voltage <sup>(Note 3)</sup>   | $V_C$     | $I_{PP}=4A, t_p=8/20\mu s$ |      | 10   |      | V        |
| Junction Capacitance                   | $C_J$     | $V_R=2.5V, f=1MHz$         |      | 0.35 | 0.5  | pF       |

Note:

1. TLP Parameter:  $Z_0=50\Omega, t_p=100ns, t_r=2ns$ , Averaging Window from 60ns to 80ns.  $R_{DYN}$  is Calculated from 4A to 16A.
2. Contact Discharge Mode, According to IEC61000-4-2.
3. Non-repetitive Current Pulse, According to IEC61000-4-5.

## Curve Characteristics

Fig. 1 - 8 X 20µs Pulse Waveform

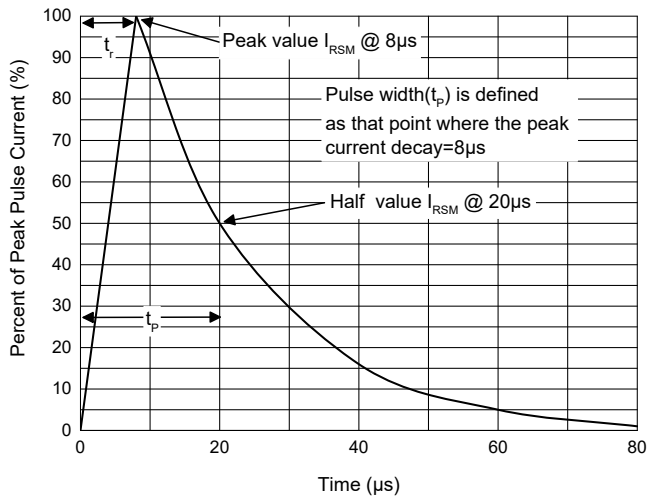


Fig. 2 - Non-Repetitive Peak Pulse Power

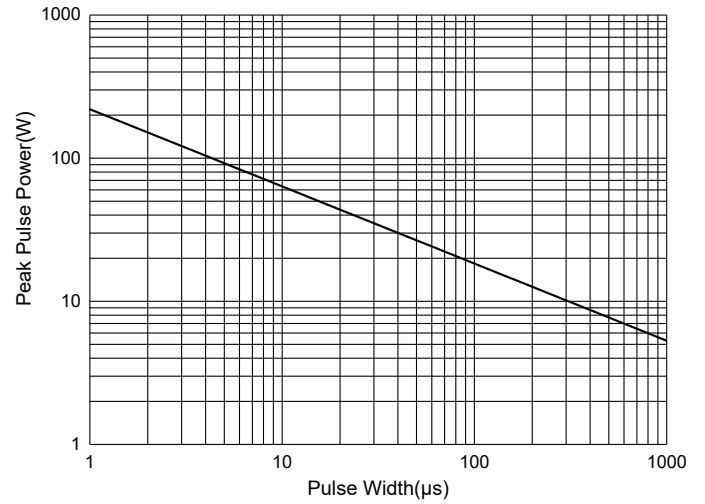


Fig. 3 - Capacitance Characteristics

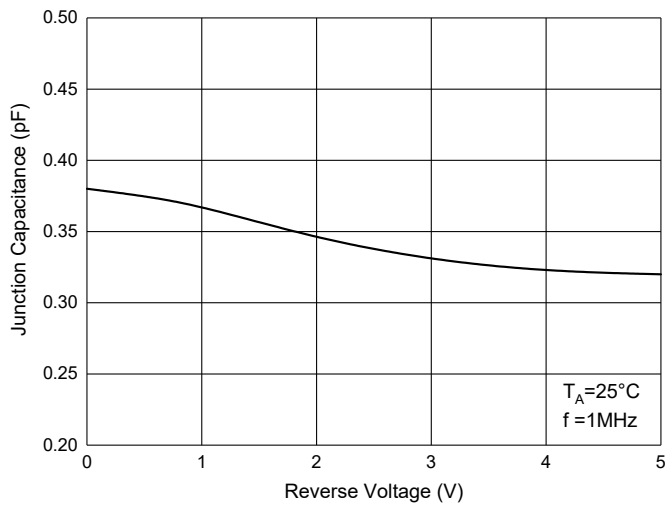


Fig. 4 - Clamping Voltage Characteristics

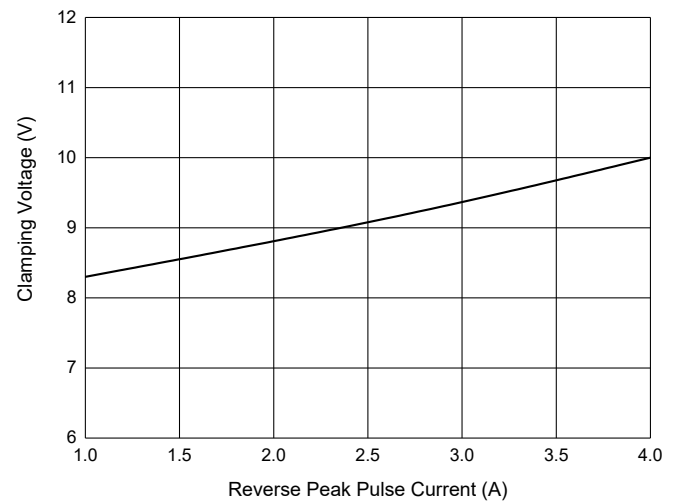


Fig. 5 - Pulse Derating Curve

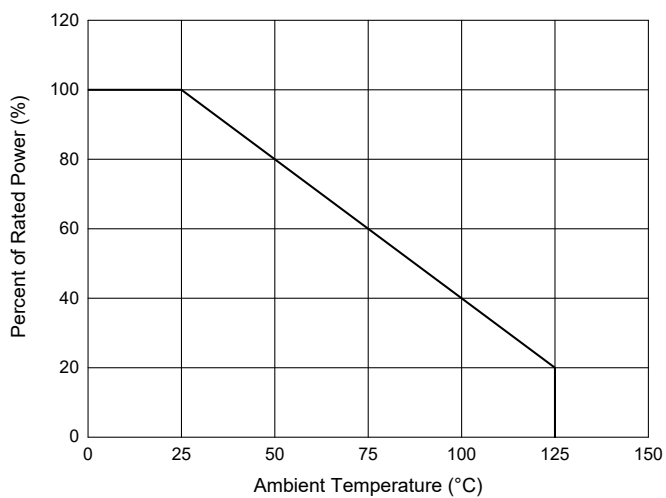


Fig. 6 - TLP Measurement

